NSN 5961-01-181-9050



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-181-9050 **Inclosure Material:** Metal **Overall Length:** 0.758 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.677 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.5 emitter to base voltage, static, collector open and 240.0 collector to base voltage/static/emitter open and 190.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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